

## Supplementary Information

### **Enhanced dielectric properties and actuated strain of elastomer composites with dopamine-induced surface functionalization**

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**Table S1** Comparing actuated strain of 50 phr BT-PDA/HNBR composite with other EAP actuators

Material	Prestrain (x,y) (%)	Actuated strain <sup>a</sup> (%)	Field Strength <sup>a</sup> (MV/m)	Ref.
VHB 4910	540, 75	215	239	1
VHB 4905	300, 300	200	480	2
Silicone ENP SEBS161 (5-30 wt%)	300, 300	180-30	32-133	3
Silicone ENP SEBS 217(5-30 wt%)	300, 300	245-47	22-98	3
VHB 4910 acrylic	300, 300	158	412	1
VHB4910/poly(1,6-hexanediol diacrylate)	275, 275	233	300	4
HS3	280, 0	117	128	1
Silicone-based prototype	200% <sup>b</sup>	18.31	96	5
TiO <sub>2</sub> /SEBS	100, 100	12	27.5	6
PMMA-PnBA-PMMA	100, 100	12	4.5	7
Silicone+30 wt%TiO <sub>2</sub>	100, 100	11	10	8
PDMS/PHT	100, 100	7.6	8	9
polyurethane-based prototype	100% <sup>b</sup>	2.04	127	5
CF19-218	100, 0	63	181	1
HS3 silicone	68, 68	93	110	1
CF19-2186 silicone	45, 45	64	350	1
DC 3481(5%81-R)/20 wt%CPO	40, 40	11	27	10
CF19-2186 silicone	15, 15	33	160	1
VHB 4910 acrylic	15, 15	40	55	1

HS3 silicone	14, 14	69	72	1
Allyl-cyano/SiR	10, 10	7	20	11
TiO <sub>2</sub> /PDMS	5, 5	18	50	12
DOP/HNBR <sup>c</sup>	0, 0	22	30	13
Dipole/PDMS	0, 0	14.8	1.3	14
TiO <sub>2</sub> /PDMS/DMSO	0, 0	13	30	15
PANI@PDVB/PDMS	0, 0	12	54	16
PEG/PDMS	0, 0	11.5	40	17
BaTiO <sub>3</sub> /CB/PDMS	0, 0	7.46	30	18
PANI-g-PolyCuPc-g-PU	0, 0	7	23	19
23 wt% PANI/P(VDF-TrFE-CTFE)	0, 0	1.5 <sup>d</sup>	9.5	20
14PANI/15PolyCuPc/85PU	0, 0	9.3 <sup>d</sup>	20	21
SEBS-MA grafted PANI	0, 0	1.4	27	22
NBR/TiO <sub>2</sub> /DOP	0, 0	3.04	20	23
18.26% v/v graphite/Polyurethane	0, 0	0.037	0.75	24
5 wt% CNTs/PDMS	0, 0	4.4	1.5	25
P(VDF-TrFE)/40 wt% CuPc	0, 0	1.91	13	26
Silicone oil/PMN/PDMS	0, 0	7.4	40	27
CNT/P(VDF-TrFE-CFE)	0, 0	2.5	72	28
P(VDF-TrFE-CFE)	0, 0	4.5	130	29
LC gels	0, 0	2.1	25	30
Polyester elastomer	0, 0	11.9	15.6	31
50 phr BT-PDA/HNBR	0, 0	20	45	

<sup>a</sup>Estimated from graphical data in cited reference, when there is no tabular was

provided; <sup>b</sup>The axial prestrain; <sup>c</sup>The dielectric elastomer was produced by us; <sup>d</sup>The longitudinal strain.

As getting a high actuated strain under the condition of prestrain-free is a big object for researchers, we compared the actuated strain of 50 phr BT-PDA/HNBR composite with those of other dielectric elastomers reported in the literature under the condition of prestrain-free. It can be easily observed that the actuated strain (20%) of 50 phr BT-PDA/HNBR composite is relatively high (DOP/HNBR dielectric elastomer was also produced by us), showing an obvious advantage in practical application.

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